

## Planar magnetic sensing Hall effect sensor

### 1. Features

- Automotive AEC-Q100 Qualified
- Planar magnetic sensing-effect ICs
- Supports a wide voltage range:
  - 2.8V to 40V
- Wide operating temperature range:
  - -40°C to 150°C
- Current limited open drain output: 40mA
- Reverse battery protection: -28V
- Output short-circuits and overvoltage protection
- High EMC immunity
- Symmetrical latch switch-points
- Solid-state reliability
- Small package:
  - 3-pin SOT23-3L (SO)

### 2. Applications

- Automotive and industrial safety systems
- Industrial motors/encoders
- Trunk/door/liftgate/wiper motors
- Electronic power steering (EPS)
- Transmission actuators
- Automotive seat/sunroof motors

### 3. Description

The SC2498T is a planar magnetic sensing Hall - effect latch designed with BCD process technology. It supports an operating voltage range from 2.8V to 40V. The device integrates a voltage regulator, a Hall sensor with a dynamic offset cancellation system, a Schmitt trigger, and an open - drain output driver in a single package. The SC2498T has passed the AEC-Q100 certification, is highly suitable for automotive applications, and complies with the ISO 26262:2011 ASIL A standard. This device has temperature stability and is suitable for operating within a working temperature range of -40°C to 150°C. It also has an overvoltage protection function and can operate directly powered by an automotive battery. Additionally, it can prevent ground short - circuits by limiting the output current until the short - circuit fault is eliminated. This device is particularly suitable for operating scenarios powered by unregulated power supplies.

The SC2498T adopts a 3 - pin SOT23 - 3L plastic package, and it is a 100% lead - free package with matte tin - plated pins.



SOT-23-3L

Fig.1 Package Outline

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## 4. Terminal Configuration

3-Terminal SOT-23  
SO Package  
(Top View)

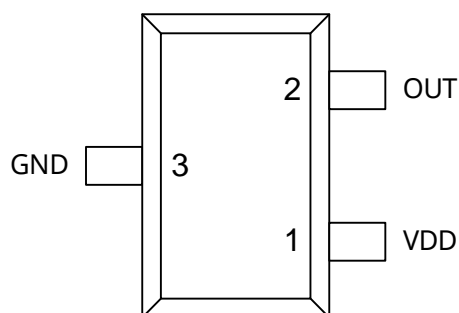


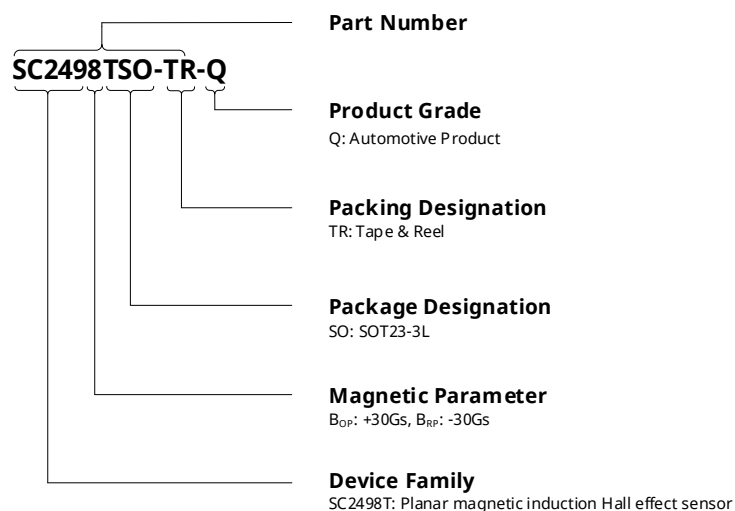
Fig.2 Terminal Configuration

Terminal		Type	Description
Name	SO		
VDD	1	Power	2.8V to 40V power supply
GND	3	Ground	Ground terminal
OUT	2	Output	Open-drain output. The open drain requires a pull-up resistor

## 5. Ordering Information

Ordering Information	Mark	B <sub>OP</sub> (Gs)	B <sub>RP</sub> (Gs)	Ambient, (°C)	Package	Packing	Quantity
SC2498TSO-TR-Q	2498T	+30	-30	-40~150	SOT23-3L	Reel	3000/reel

### Ordering Information Format



## 6. Absolute Maximum Ratings

Operating temperature range (unless otherwise specified) <sup>(1)</sup>

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>DD</sub>	Power supply voltage	Resistance $\geq 200\Omega$ , no more than 5 minutes	-28	60	V
V <sub>OUT</sub>	Output terminal voltage	1.2 k $\Omega$ pull up resistor, not exceed 5 min	-0.5	60	V
I <sub>SINK</sub>	Output terminal current sink		0	40	mA
T <sub>A</sub>	Operating ambient temperature		-40	150	°C
T <sub>J</sub>	Maximum junction temperature		-55	165	°C
T <sub>STG</sub>	Storage temperature		-65	175	°C

Note:

(1) Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## 7. ESD Protection

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>ESD_HBM</sub>	HBM	According to: standard AEC-Q100-002 HBM	-8	+8	kV
V <sub>ESD_CDM</sub>	CDM	According to: standard AEC-Q100-011 CDM	-750	+750	V

## 8. Thermal Characteristics

Symbol	Parameter	Test Conditions	Rating	Units
R <sub>θJA</sub>	SO Package thermal resistance	Single-layer PCBS, JEDEC 1s0p are defined in JESD 51-3	300 <sup>(1)</sup>	°C/W

Note:

(1) Maximum voltage must be adjusted for power dissipation and junction temperature, see Thermal Characteristics.

## 9. Operating Characteristics

### 9.1. Electrical Characteristics

Within the operating temperature range,  $V_{DD} = 5V$  (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Units
$V_{DD}$	Operating voltage <sup>(2)</sup>	$T_J < T_{J(Max.)}$	2.8	5.0	40	V
$I_{DD}$	Operating supply current	$V_{DD}=2.8$ to $40$ V, $T_A=25^\circ C$	3.5	4.1	7	mA
$UVLO_H$	Under Voltage Lockout High	$B > B_{OP} + 2.0mT$ , $V_{DD}$ Rising From 2.5V	-	2.7	-	V
$UVLO_L$	Under Voltage Lockout Low	$B > B_{OP} + 2.0mT$ , $V_{DD}$ Decreasing From 3.0V	-	2.5	-	V
$UVLO_{HYS}$	Under Voltage Hysteresis	$UVLO_H - UVLO_L$	-	0.2	-	V
$t_{on}$	Power-on time	$V_{DD} \geq 5V$	-	25	40	$\mu s$
$I_{QL}$	Off-state leakage current	Output Hi-Z	-	-	3	$\mu A$
$V_{SAT}$	Output saturation voltage	$I_O = 20mA$	-	0.14	0.40	V
OCP	Over current protection	Output on $V_{PULL-UP} < 30V$	30	50	70	mA
$t_d$	Output delay time	$B = B_{RP}$ to $B_{OP}$	-	15	25	$\mu s$
$t_r$	Output rise time(10% to 90%)	$R1 = 1Kohm$ , $C_o = 50pF$	-	0.2	1	$\mu s$
$t_f$	Output fall time(90% to 10%)	$R1 = 1Kohm$ , $C_o = 50pF$	-	0.1	1	$\mu s$

Note:

(1) Typical values are defined at  $T_A = +25^\circ C$  and  $V_{DD} = 5V$

(2) Maximum voltage must be adjusted for power dissipation and junction temperature, see Thermal Characteristics

## 9.2. Magnetic Characteristics

Within the operating temperature range,  $V_{DD} = 5.0V$  (unless otherwise specified)

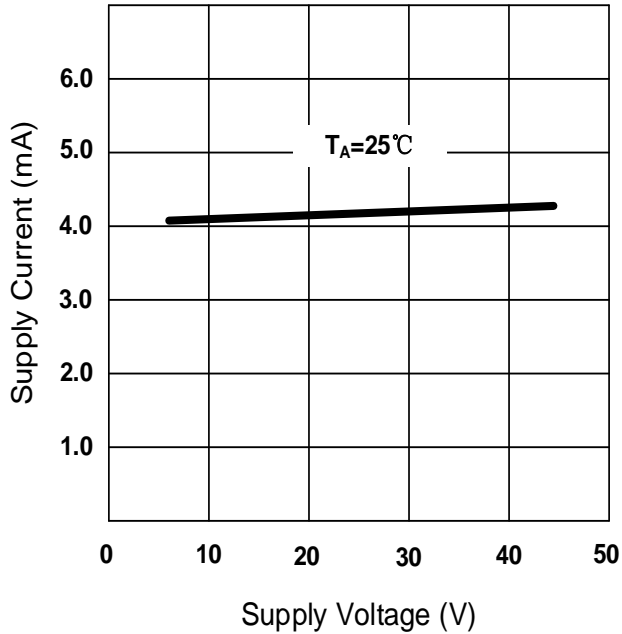
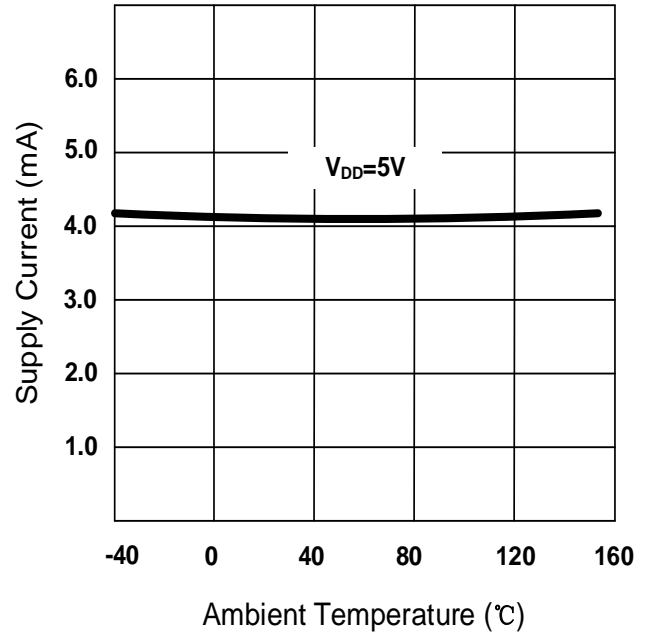
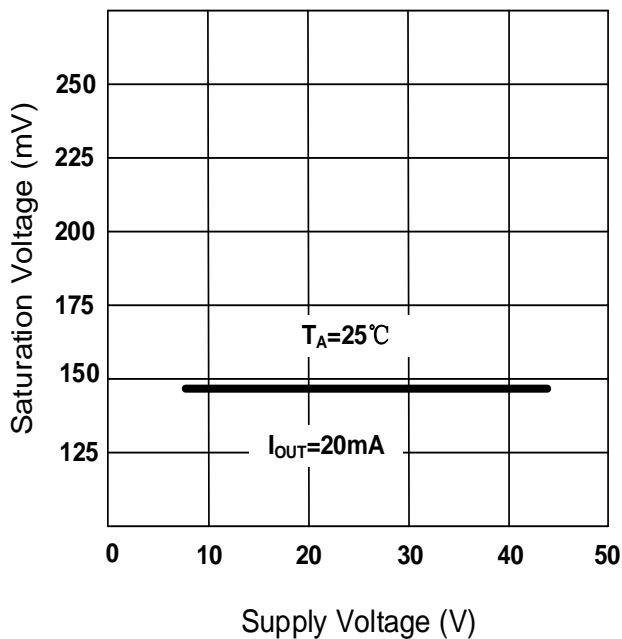
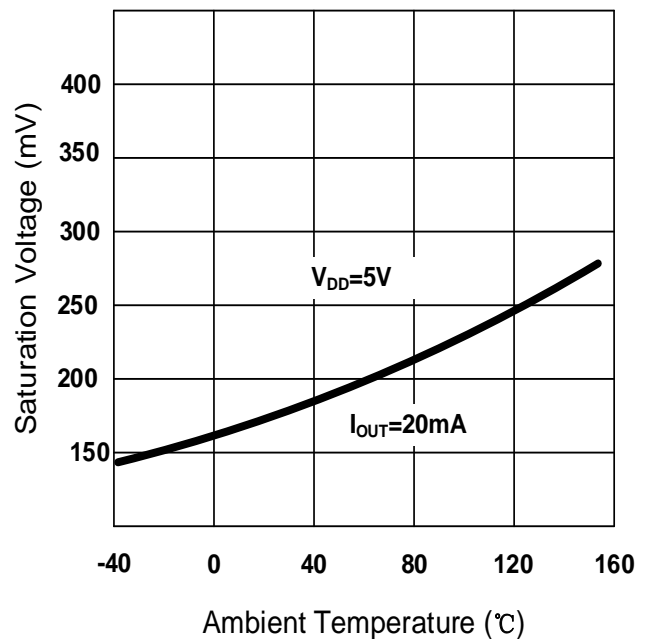
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$f_{BW}$	BW		20	-	-	kHz
<b>SC2498TSO +3.0<sup>(1)</sup> /-3.0 mT<sup>(2)</sup></b>						
$B_{OP}$	Operating point	$T_A = 25^\circ C$	+1.5	+3.0	+4.5	mT
$B_{RP}$	Release point		-4.5	-3.0	-1.5	mT
$B_{HYS}$	Hysteresis		3.0	6.0	9.0	mT
$B_{HYS}$	Magnetic offset	$B_O = (B_{OP} + B_{RP})/2$	-1.5	0	+1.5	mT

Note:

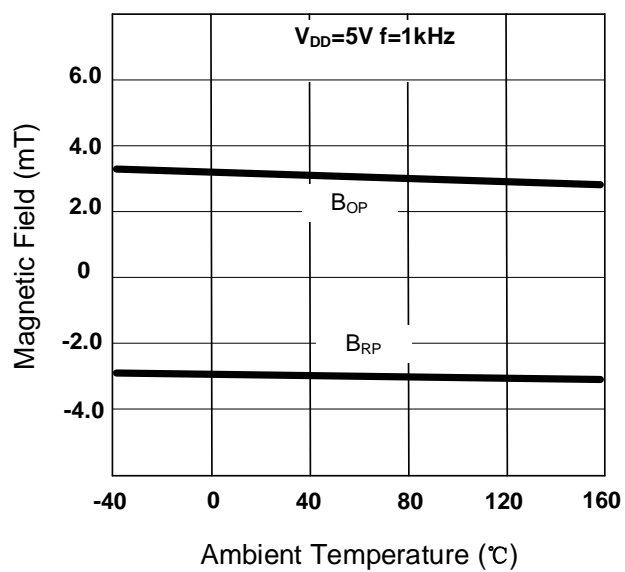
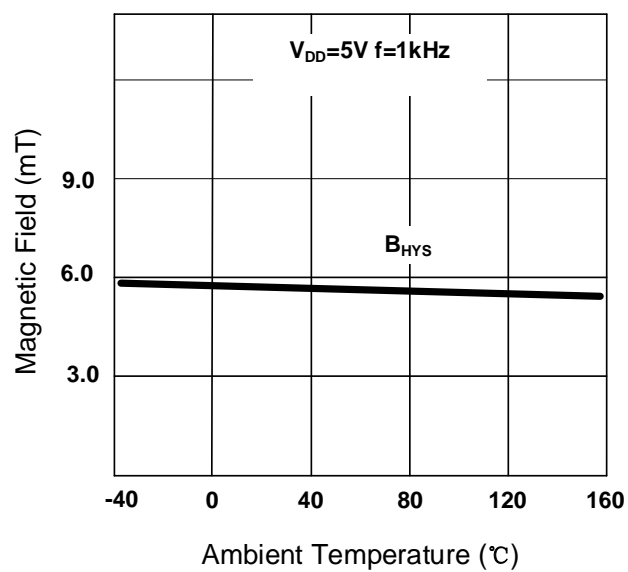
(2) Magnetic flux density,  $B$  is indicated as a negative value for North-polarity magnetic fields, and as a positive value for South-polarity magnetic fields

(1) 1mT=10Gs

## 10. Typical Characteristics

 $I_{DD}$  vs  $V_{DD}$  $I_{DD}$  vs  $T_A$  $V_{Q(sat)}$  vs  $V_{DD}$  $V_{Q(sat)}$  vs  $T_A$ 



**B<sub>OP</sub> and B<sub>RP</sub> vs T<sub>A</sub>****B<sub>HYS</sub> vs T<sub>A</sub>**

## 11. Block Diagram

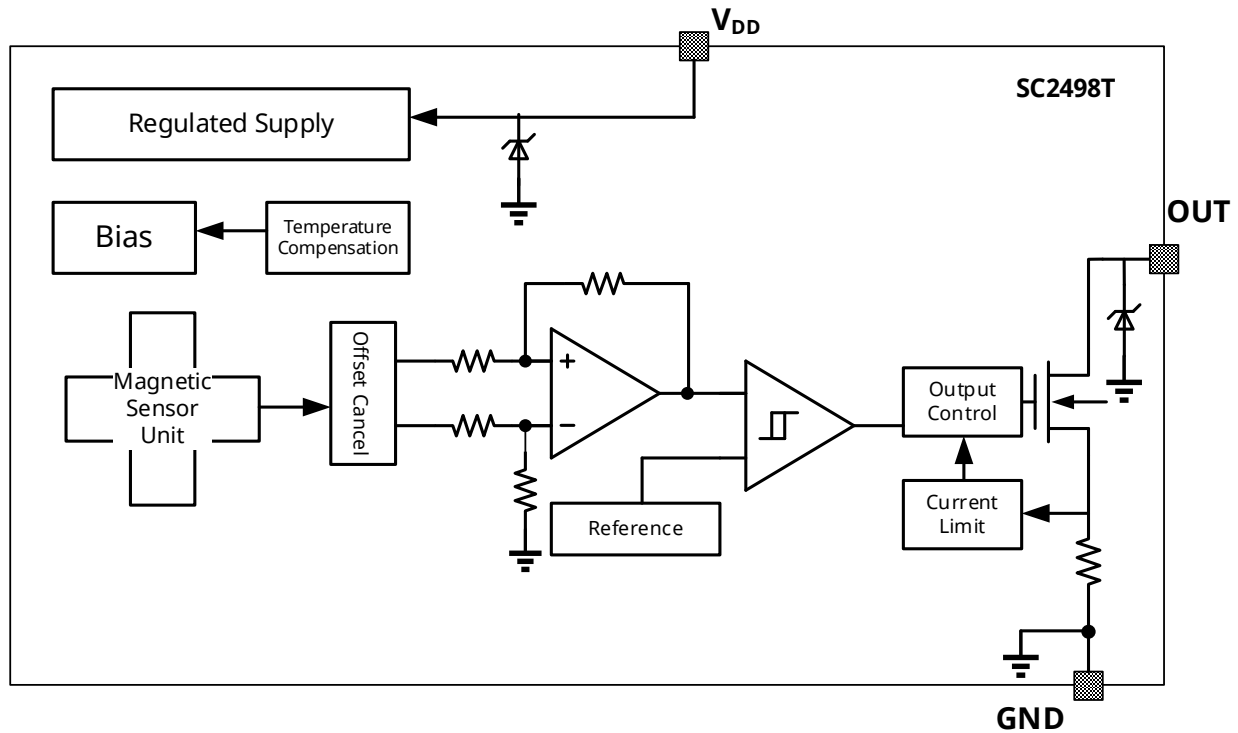


Fig.3 Function Block Diagram

## 12. Function Description

The SC2498T is a planar magnetic sensing Hall - effect sensor integrated circuit with an open - drain output. The open - drain output is an N - channel metal - oxide - semiconductor (NMOS) transistor that responds to the magnetic field. For the SC2498T, the direction of the applied magnetic field is parallel to the marked side. These devices are packaged in a small outline (SO) package, which is a 3 - pin surface - mount configuration.

### 12.1. Field Direction Definition

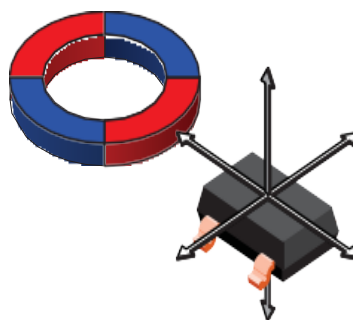


Fig. 4 Magnetic Field Direction Definition

## 12.2. Transfer Function

Powering-on the device in the hysteresis region, less than  $B_{OP}$  and higher than  $B_{RP}$ , allows an indeterminate output state. The correct state is attained after the first excursion beyond  $B_{OP}$  or  $B_{RP}$ .

SOT23-3L package as an example, if the field strength is greater than  $B_{OP}$ , then the output is pulled low. If the field strength is less than  $B_{RP}$ , the output is released.

$B_{OP}$ —magnetic threshold for activation of the device output, turning in ON (low) state.

$B_{RP}$ —magnetic threshold for release of the device output, turning in OFF (high) state.

$$B_{HYS} = B_{OP} - B_{RP}$$

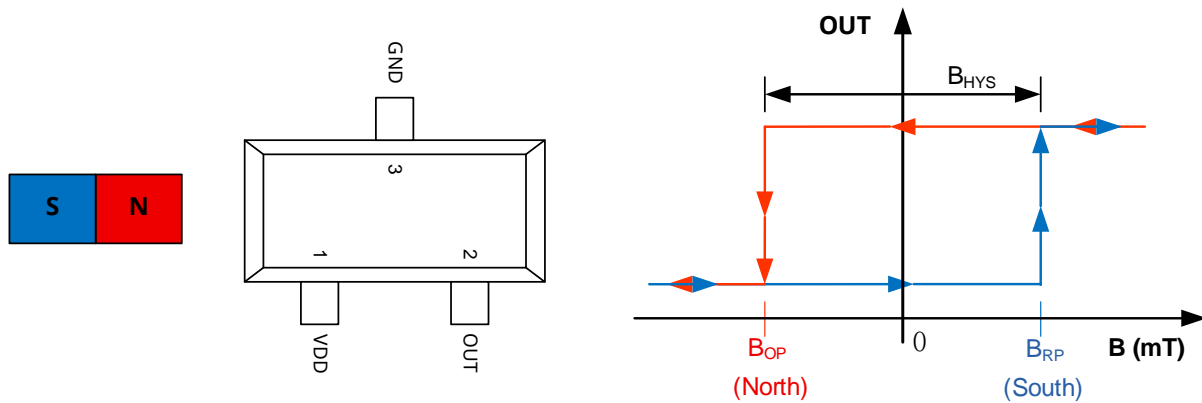


Fig.5 Magnetic Transfer Function

### 13. Typical Application

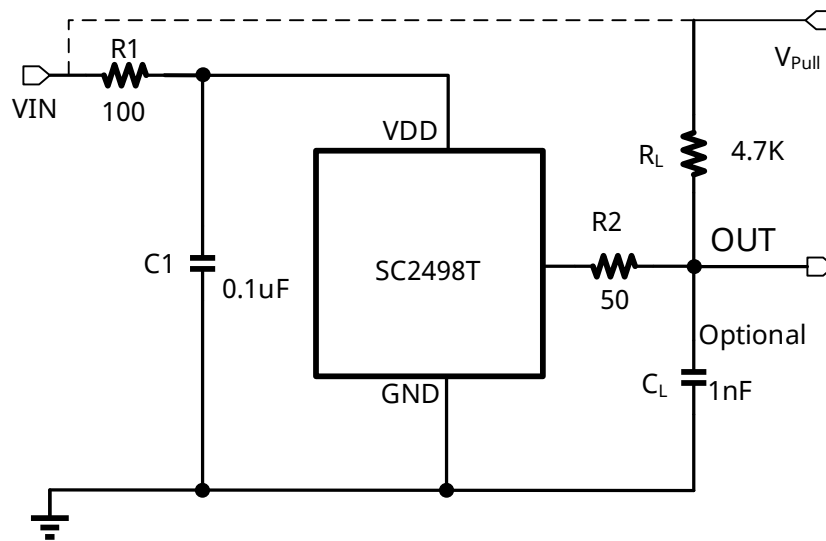


Fig. 6 Typical Application Circuit

The SC2498T contains an on-chip voltage regulator and can operate over a wide supply voltage range. In applications that operate the device from an unregulated power supply, transient protection must be added externally. For applications using a regulated line, EMI/RFI protection may still be required. It is recommended that  $C_1$  capacitor be connected to the ground in parallel near the  $V_{DD}$  power end of the chip, with a typical value of  $0.1\mu\text{F}$ . At the same time in the external optional series resistor  $R_1$  and output capacitance  $C_L$  used for enhanced protection circuit, its typical values for  $100\Omega$  and  $1\text{nF}$ .

The SC2498T device output stage uses an open-drain NMOS, and it is rated to sink up to  $40\text{mA}$  of current. For proper operation, calculate the value of the pull-up resistor  $R_L$  is required. The size of  $R_L$  is a tradeoff between OUT rise time and the load capacity when OUT is pulled low. A lower current is generally better, however faster transitions and bandwidth require a smaller resistor for faster switching.

Select a value for  $C_L$  based on the system bandwidth specifications as:

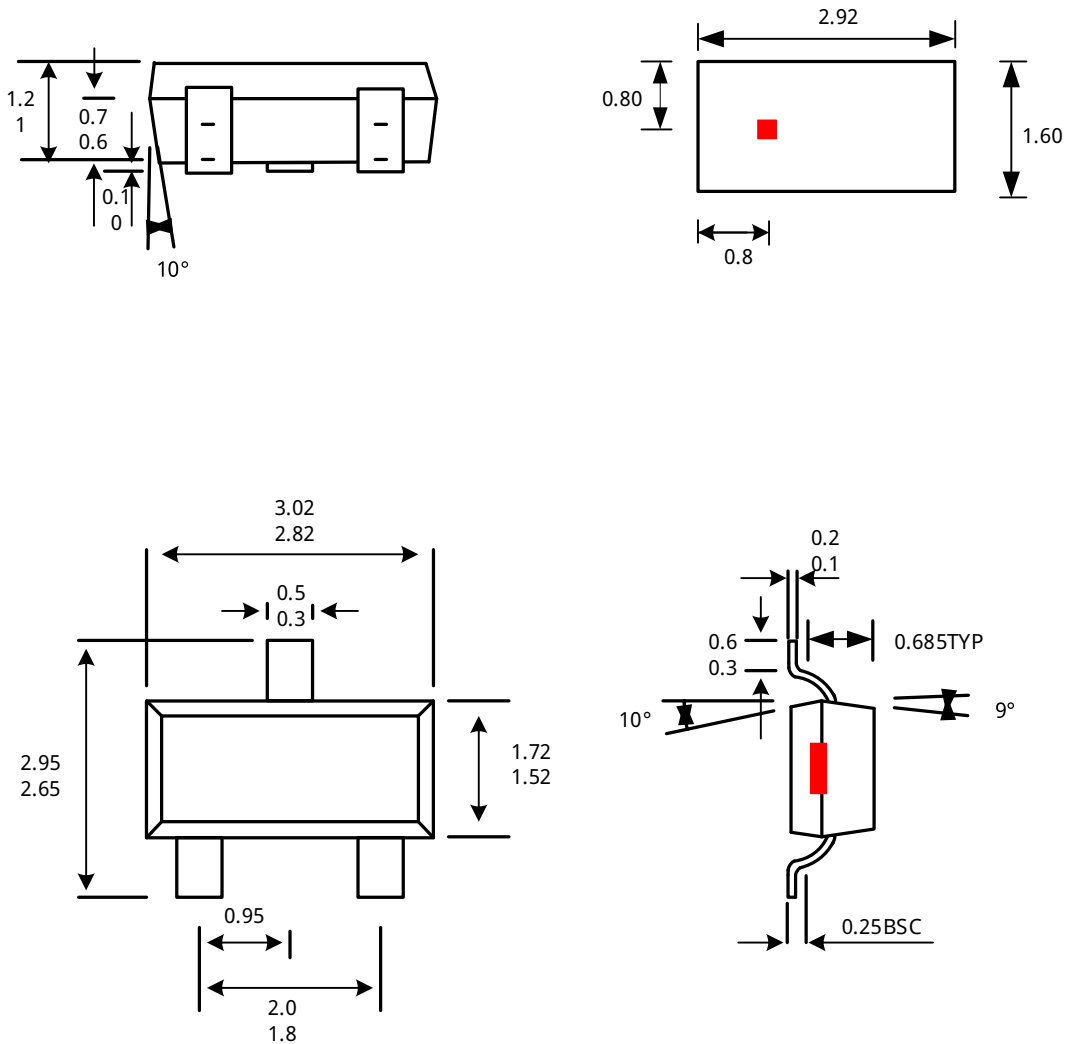
$$C_L < \frac{1}{2\pi \times R_L \times 2 \times f_{BW}(\text{Hz})}$$

$V_{PULL}$  is not restricted to  $V_{DD}$ , and could be connected to other voltage reference. The allowable voltage range of this terminal is specified in the Absolute Maximum Ratings.

## 14. Package Information SO

3-Terminal  
SO Package

Unit:mm



**Notes:**

- (1) Exact body and lead configuration at vendor's option within limits shown.
- (2) Height does not include mold gate flash.
- (3) The red mark is Hall element.

Where no tolerance is specified, dimension is nominal.

## 15. Revision History

Revision	Date	Description
Rev.E0.1	2023-06-10	Preliminary datasheet
Rev.E0.2	2023-07-17	Unified format
Rev.E0.3	2023-08-21	Revised some description
Rev.A1.0	2023-08-24	Upgrade Version
Rev.A1.1	2024-06-11	Update Sensor Position
Rev.A1.2	2025-07-05	Release with updated format